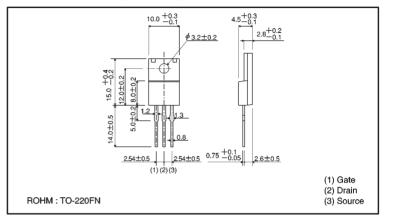
# Transistors

# Switching (450V, 7A) 25к2299N

## Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Wide SOA (safe operating area).
- 4) Gate-source voltage (V\_{GSS}) guaranteed to be  $\pm 30$ V.
- 5) Easily designed drive circuits.
- 6) Easy to parallel.

Structure
 Silicon N-channel
 MOSFET



External dimensions (Units: mm)

### •Absolute maximum ratings (Ta = $25^{\circ}$ C)

		<u> </u>		
Parameter		Symbol	Limits	Unit
Drain-source voltage		VDSS	450	V
Gate-source voltage		Vgss	±30	V
Drain ourrent	Continuous	lo	7	А
Drain current	Pulsed	DP*	28	А
Reverse drain	Continuous	<b>I</b> DR	7	А
current	Pulsed	Idrp*	28	А
Total power dissipatio			30	W
Channel temperature		Tch	150	Ĉ
Storage temperature		Tstg	-55~+150	ĉ

\* Pw $\leq$ 10  $\mu$ s, Duty cycle $\leq$ 1%

#### Packaging specifications

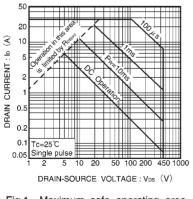
	Package	Bulk
Туре	Code	—
	Basic ordering unit (pieces)	500
2SK2299N		$\bigcirc$

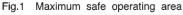
#### •Electrical characteristics (Ta = $25^{\circ}$ C)

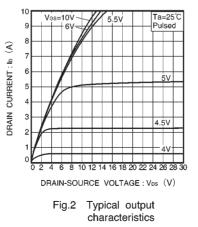
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Gate-source leakage	lass	—	—	±100	nA	$V_{GS}=\pm 30V, V_{DS}=0V$
Drain-source breakdown voltage	V(BR)DSS	450	_	_	V	lo=1mA, Vgs=0V
Zero gate voltage drain current	loss	_	_	100	μA	V <sub>DS</sub> =450V, V <sub>GS</sub> =0V
Gate threshold voltage	VGS(th)	2.0	-	4.0	V	Vos=10V, Io=1mA
Static drain-source on-state resistance	RDS(on)	_	0.85	1.1	Ω	ID=4.0A, VGS=10V
Forward transfer admittance	Yfs  *	3.0	5.5	_	S	ID=4.0A, VDS=10V
Input capacitance	Ciss	_	870	_	pF	V <sub>DS</sub> =10V
Output capacitance	Coss	_	180	_	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	Crss	—	40	_	pF	f=1MHz
Turn-on delay time	td(on)	_	15	_	ns	I⊳=4A, V⊳⊳≒150V
Rise time	tr	—	18	_	ns	V <sub>GS</sub> =10V
Turn-off delay time	td(off)	_	60	_	ns	R∟=37.5Ω
Fall time	tr		35	_	ns	Rg=10Ω
Reverse recovery time	trr		400	_	ns	Idr=7A, Vgs=0V
Reverse recovery charge	Qrr	_	2.5	_	μC	di/dt=100A/μs

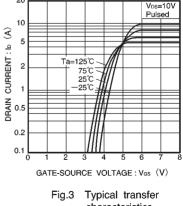
\* Pw≦300 μs, Duty cycle≦1%

#### Electrical characteristic curves







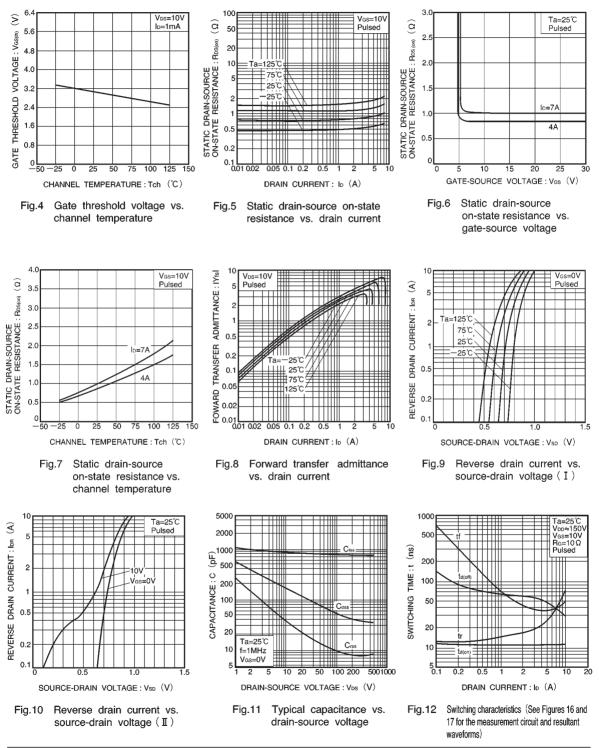


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ROHM

# Transistors



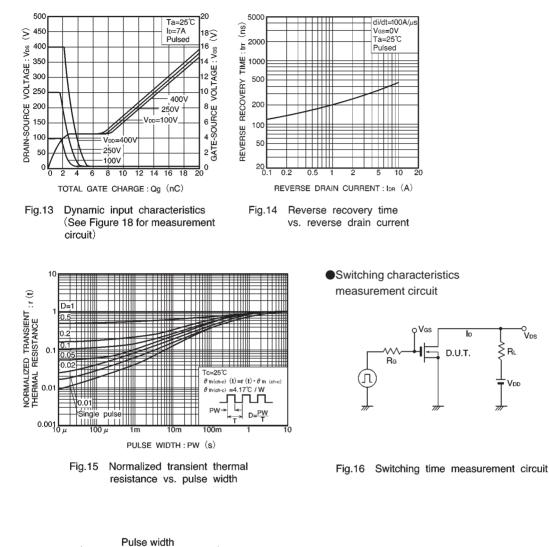
108



-O Vds

≷rι

Vdd



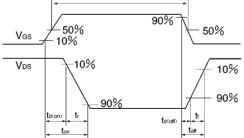


Fig.17 Switching time waveforms

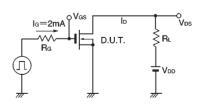


Fig.18 Gate charge measurement circuit

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